

International
IR Rectifier

SERIES IRK.166, .196, .236

STANDARD RECOVERY DIODES

NEW INT-A-pak Power Modules

Features

- High Voltage
- Electrically Isolated by DBC Ceramic (Al_2O_3)
- 3500 V_{RMS} Isolating Voltage
- Industrial Standard Package
- High Surge Capability
- Glass Passivated Chips
- Modules uses High Voltage Power diodes in four Basic Configurations
- Simple Mounting
- UL E78996 approved 

165 A
195 A
230 A

Applications

- DC Motor Control and Drives
- Battery Charges
- Welders
- Power Converters

Major Ratings and Characteristics

Parameters	IRK.166..	IRK.196..	IRK.236..	Units
$I_{\text{F(AV)}}$	165	195	230	A
@ T_{C}	100	100	100	°C
$I_{\text{F(RMS)}}$	260	305	360	A
I_{FSM} @ 50Hz	4000	4750	5500	A
@ 60Hz	4200	4980	5765	A
I^2t @ 50Hz	80	113	151	KA ² s
@ 60Hz	73	103	138	KA ² s
$I^2\sqrt{t}$	798	1130	1516	KA ² √s
V_{RRM}	400 to 1600			V
T_{J} range	-40 to 150			°C

CASE STYLE NEW INT-A-PAK



Electrical Specifications

Voltage Ratings

Type number	Voltage Code	V_{RRM} , Maximum repetitive peak reverse voltage V	V_{RSM} , Maximum non-repetitive peak reverse voltage V	I_{RRM} 150°C mA
IRK.166	04	400	500	20
IRK.196	08	800	900	
IRK.236	12	1200	1300	
	14	1400	1500	
	16	1600	1700	

Forward Conduction

Parameter	IRK.166	IRK.196	IRK.236	Units	Conditions
$I_{F(AV)}$ Max. average on-state current @ Case temperature	165 100	195 100	230 100	A °C	180° conduction, half sine wave
$I_{F(RMS)}$ Max. RMS on-state current	260	305	360	A	
I_{FSM} Maximum peak, one-cycle on-state, non-repetitive surge current	4000 4200 3350 3500	4750 4980 4000 4200	5500 5765 4630 4850	A	t = 10ms t = 8.3ms t = 10ms t = 8.3ms No voltage reappplied 100% V_{RRM} reappplied
I^2t Maximum I^2t for fusing	80 73 56 52	113 103 80 73	151 138 107 98	KA ² s	t = 10ms t = 8.3ms t = 10ms t = 8.3ms No voltage reappplied 100% V_{RRM} reappplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	798	1130	1516	KA ² √s	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.73	0.69	0.7	V	(16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), @ T_J max.
$V_{F(TO)2}$ High level value of threshold voltage	0.88	0.78	0.83		($I > \pi \times I_{F(AV)}$), @ T_J max.
r_{t1} Low level value on-state slope resistance	1.5	1.3	1.2	mΩ	(16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), @ T_J max.
r_{t2} High level value on-state slope resistance	1.26	1.2	1.07		($I > \pi \times I_{F(AV)}$), @ T_J max.
V_{FM} Maximum forward voltage drop	1.43	1.38	1.46	V	$I_{FM} = \pi \times I_{F(AV)}$, $T_J = 25^\circ\text{C}$, 180° conduction Av. power = $V_{F(TO)} \times I_{F(AV)} + r_f \times (I_{F(RMS)})^2$

Blocking

I_{RRM} Maximum peak reverse and off-state leakage current	20	mA	$T_J = 150^\circ\text{C}$
V_{INS} RMS isolation voltage	3500	V	50Hz, circuit to base, all terminals shorted, t = 1s

Thermal and Mechanical Specifications

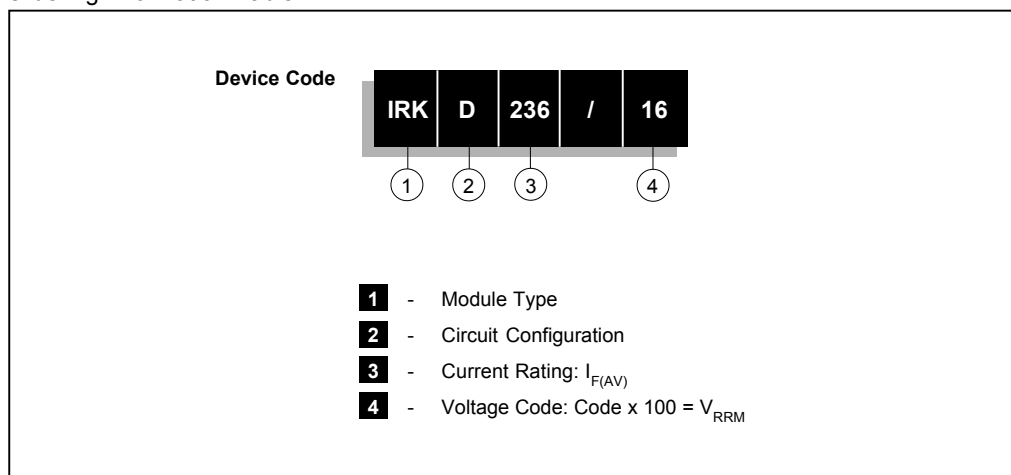
Parameter		IRK.166	IRK.196	IRK.236	Units	Conditions
T _j	Max. junction operating temperature range	-40 to 150			°C	
T _{stg}	Max. storage temperature range	-40 to 150			°C	
R _{thJC}	Max. thermal resistance, junction to case	0.2	0.16	0.14	K/W	DC operation, per junction
R _{thCS}	Max. thermal resistance, case to heatsink	0.05			K/W	Mounting surface smooth, flat and greased Per module
T	Mounting torque ± 10%	4 to 6			Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.
	IAP to heatsink busbar to IAP	4 to 6				
wt	Approximate weight	200 (7.1)			g (oz)	
Case Style		New Int-A-Pak				

 ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

Devices	Sinusoidal conduction @ T _J max.					Rectangular conduction @ T _J max.					Units
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
IRK.166	0.025	0.03	0.038	0.055	0.089	0.018	0.031	0.041	0.057	0.089	K/W
IRK.196	0.016	0.019	0.024	0.034	0.053	0.012	0.02	0.026	0.035	0.054	
IRK.236	0.009	0.010	0.014	0.018	0.025	0.008	0.012	0.015	0.019	0.025	

Ordering Information Table

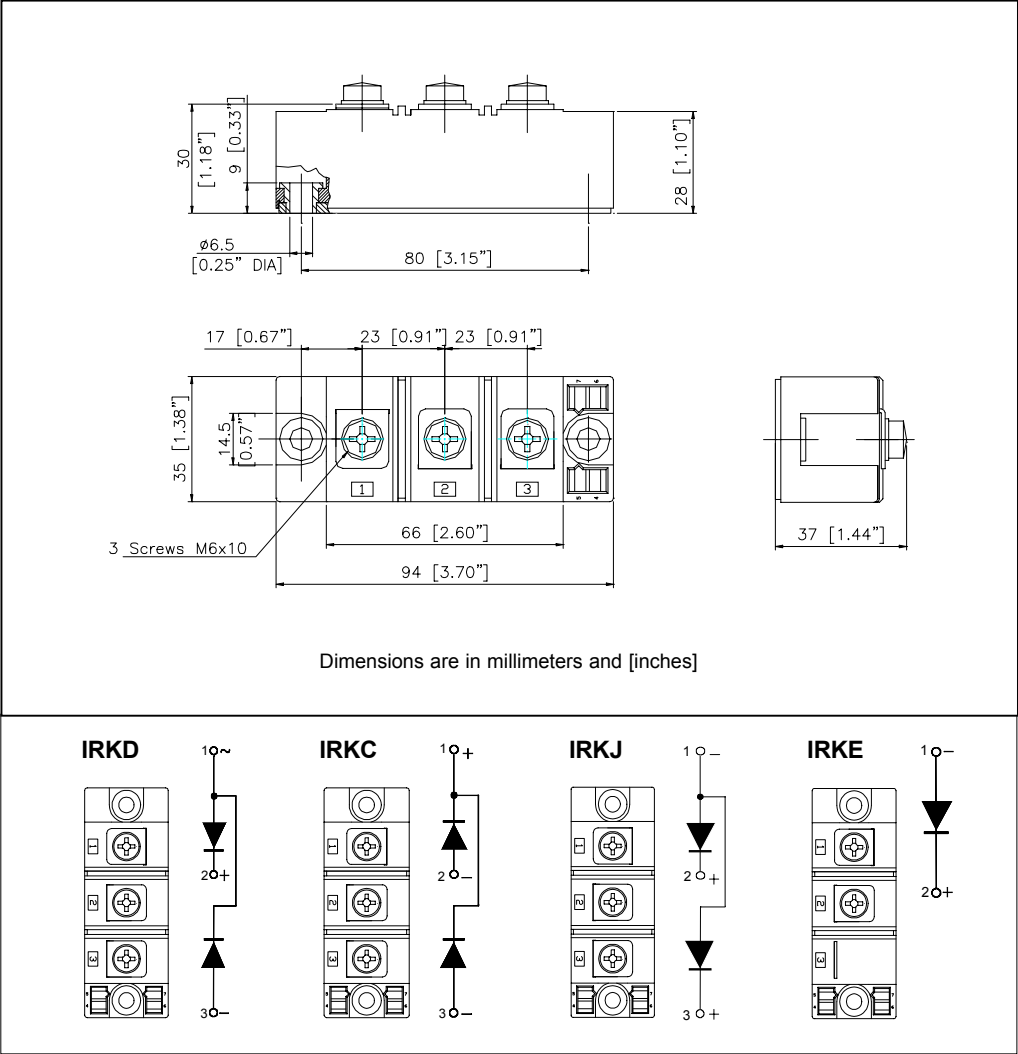


IRK.166, .196, .236 Series

Bulletin I27116 rev. C 03/02

International
IOR Rectifier

Outline Table



NOTE: To order the Optional Hardware see Bulletin I27900

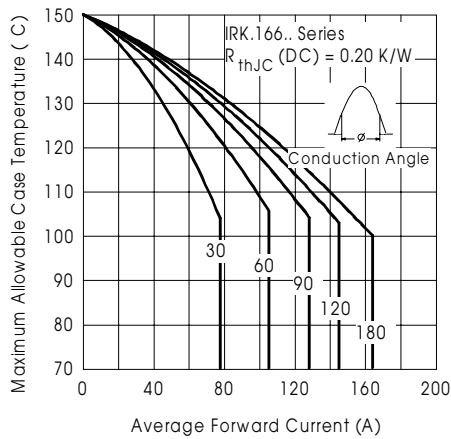


Fig. 1 - Current Ratings Characteristics

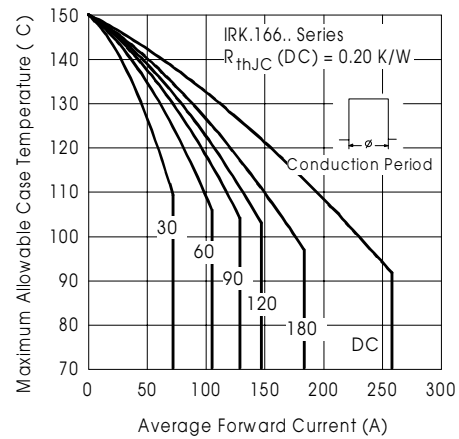


Fig. 2 - Current Ratings Characteristics

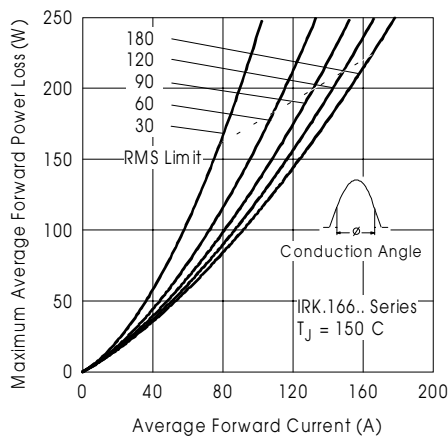


Fig. 3 - On-State Power Loss Characteristics

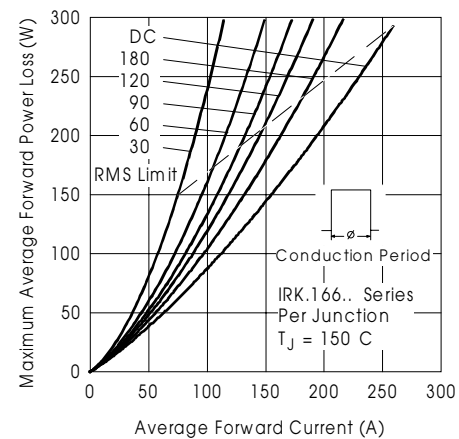


Fig. 4 - On-State Power Loss Characteristics

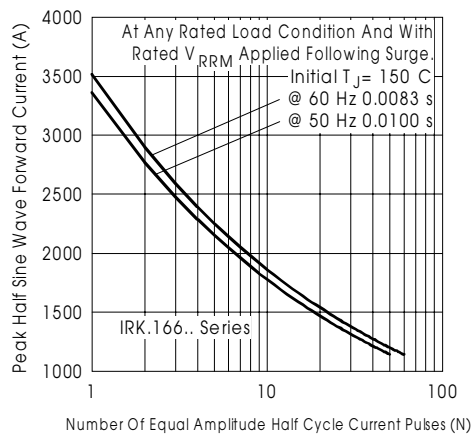


Fig. 5 - Maximum Non-Repetitive Surge Current

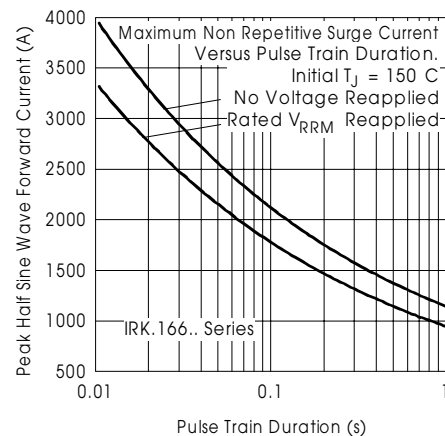


Fig. 6 - Maximum Non-Repetitive Surge Current

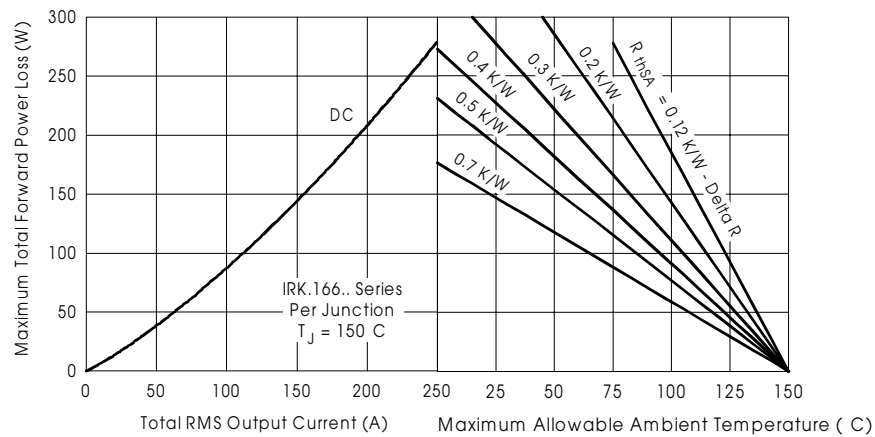


Fig.7 - On State Power Loss Characteristics

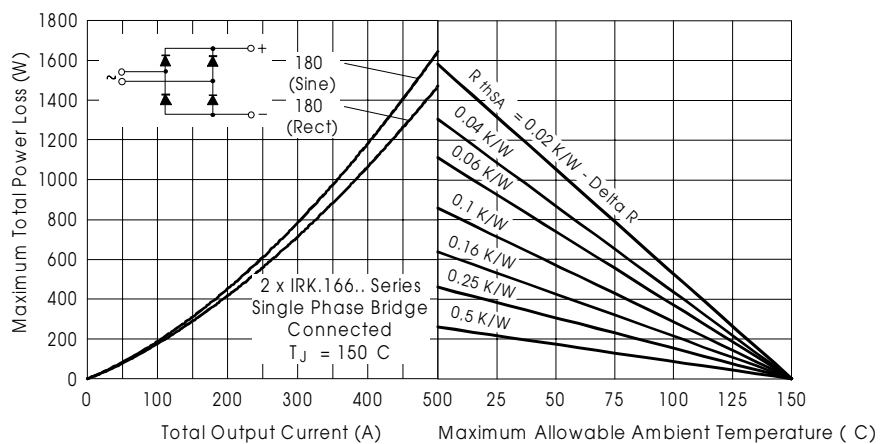


Fig.8 - On State Power Loss Characteristics

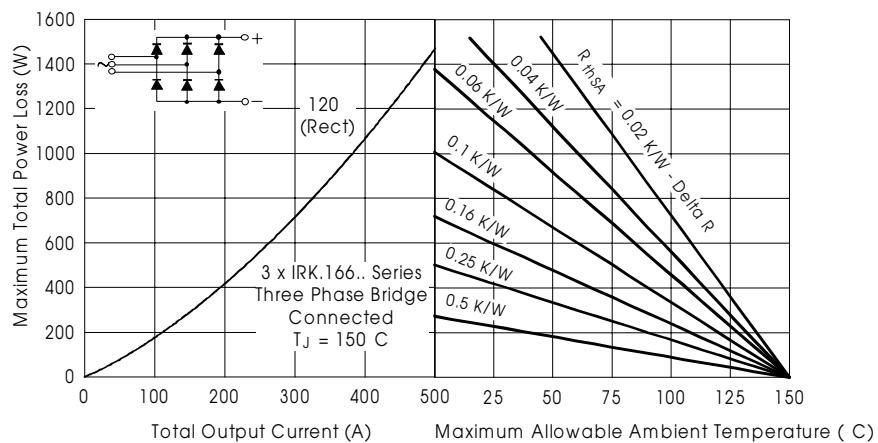


Fig.9 - On State Power Loss Characteristics

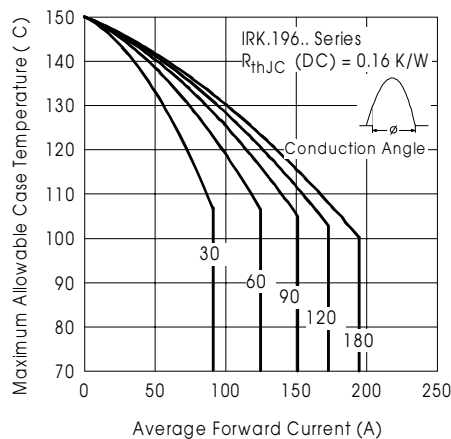


Fig. 10 - Current Ratings Characteristics

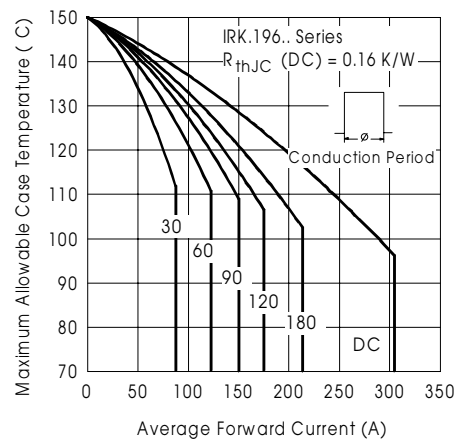


Fig. 11 - Current Ratings Characteristics

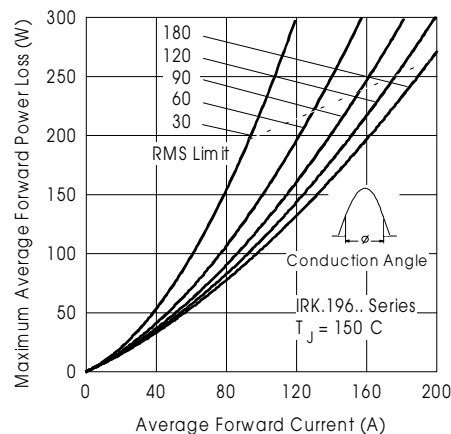


Fig. 12 - On-State Power Loss Characteristics

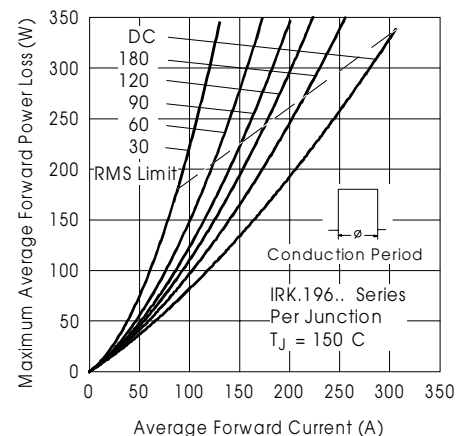


Fig. 13 - On-State Power Loss Characteristics

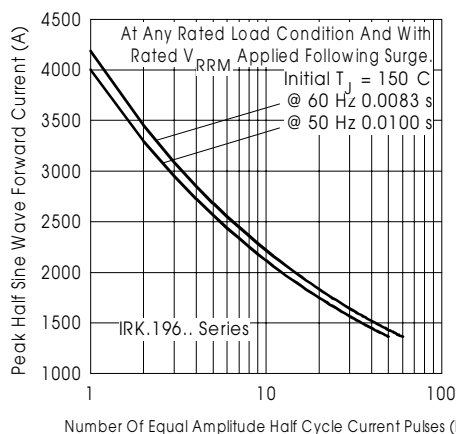


Fig. 14 - Maximum Non-Repetitive Surge Current

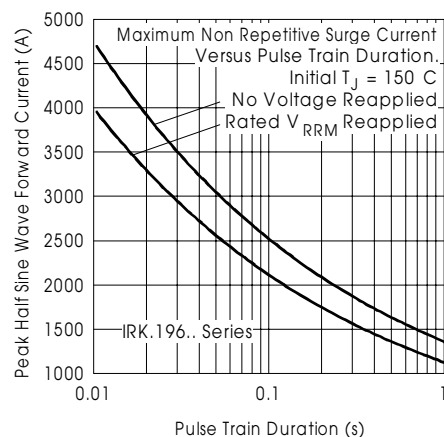


Fig. 15 - Maximum Non-Repetitive Surge Current

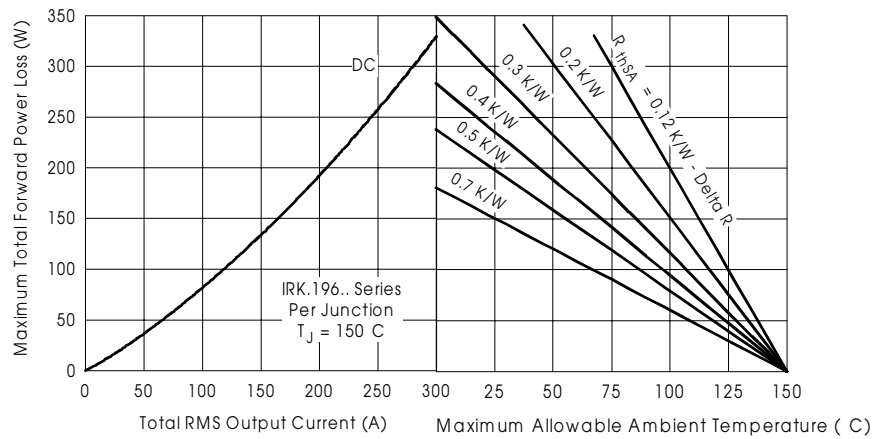


Fig.16 - On State Power Loss Characteristics

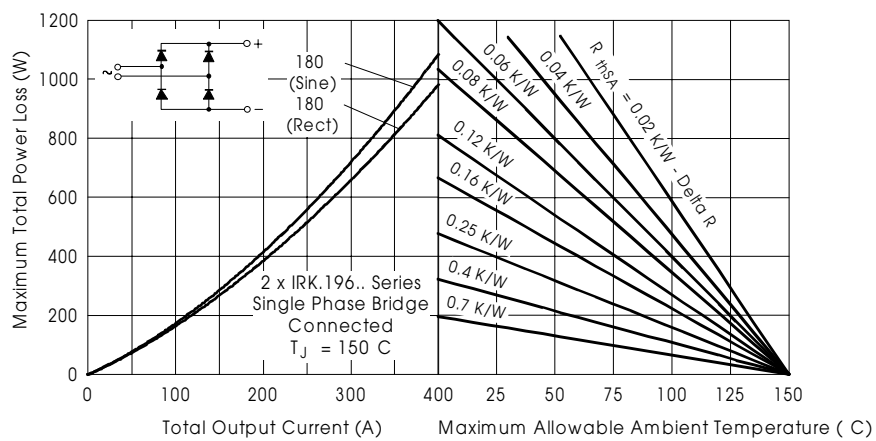


Fig.17 - On State Power Loss Characteristics

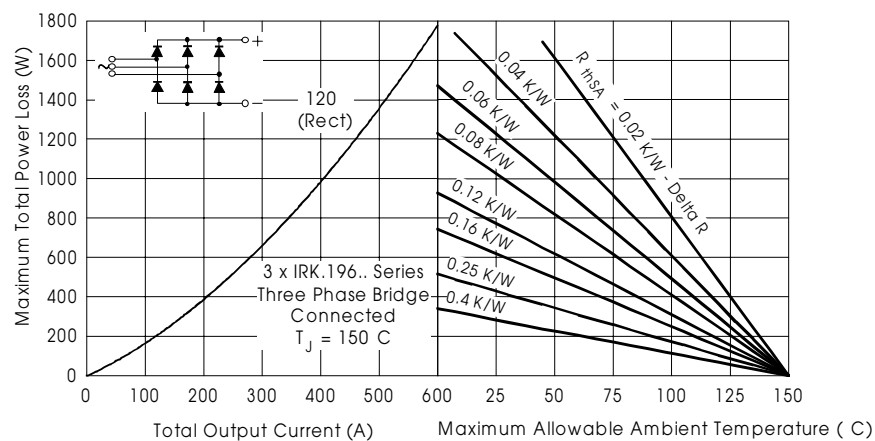


Fig.18- On State Power Loss Characteristics

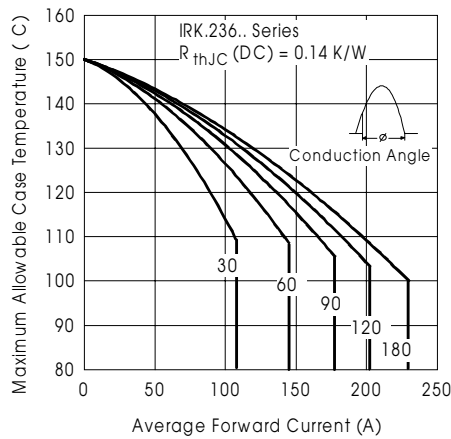


Fig. 19 - Current Ratings Characteristics

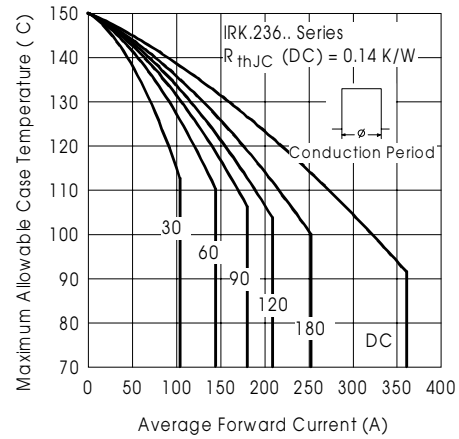


Fig. 20 - Current Ratings Characteristics

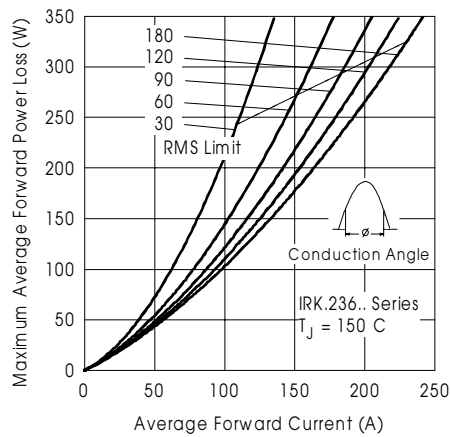


Fig. 21 - On-State Power Loss Characteristics

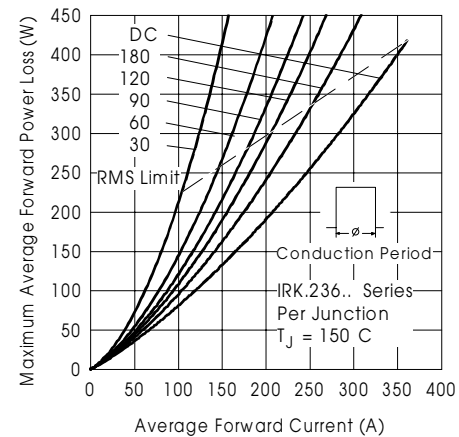


Fig. 22 - On-State Power Loss Characteristics

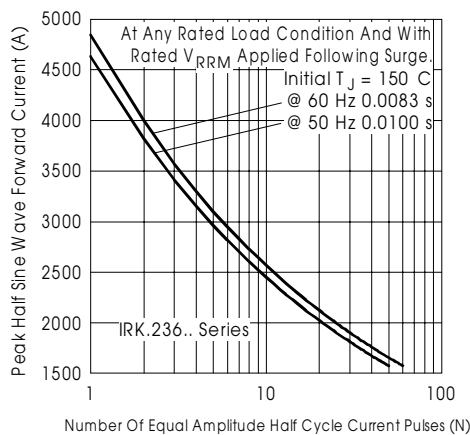


Fig.23 - Maximum Non-Repetitive Surge Current

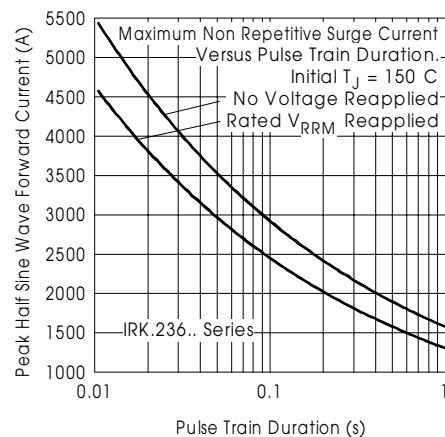


Fig. 24 - Maximum Non-Repetitive Surge Current

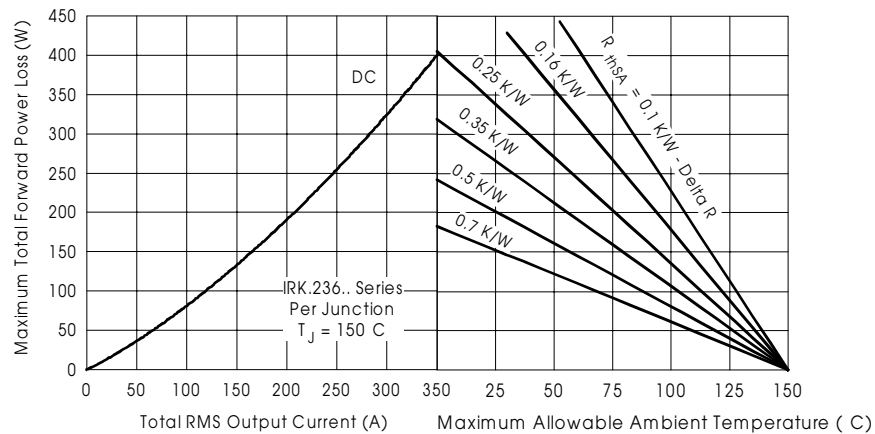


Fig.25 - On State Power Loss Characteristics

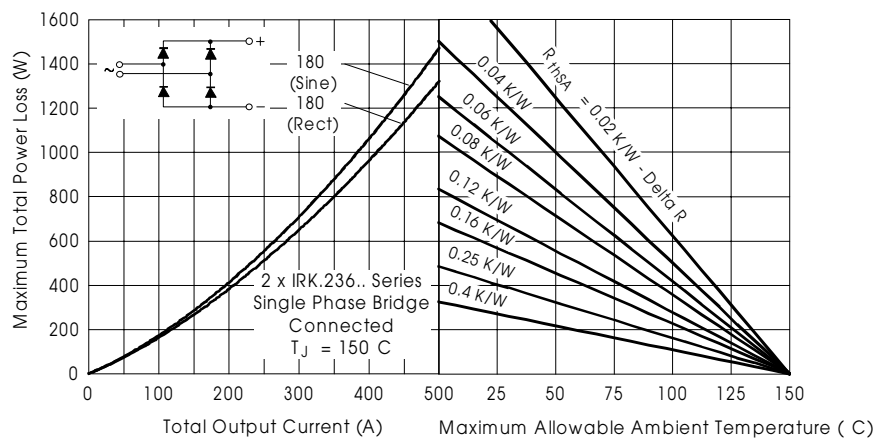


Fig.26 - On State Power Loss Characteristics

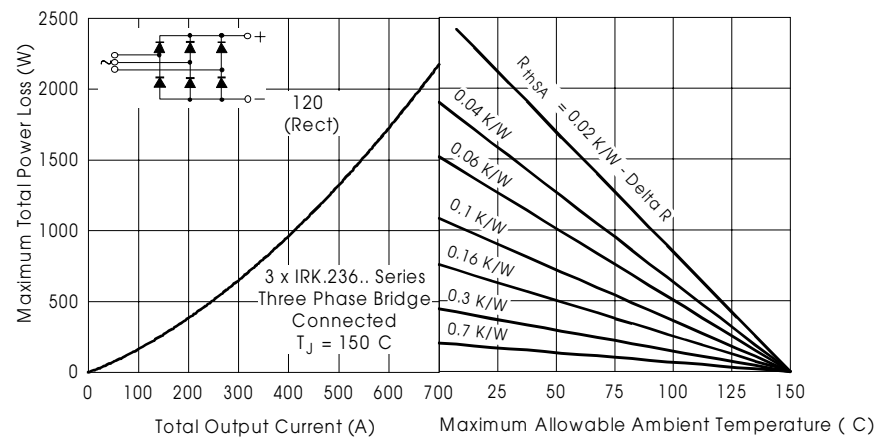


Fig.27 - On State Power Loss Characteristics

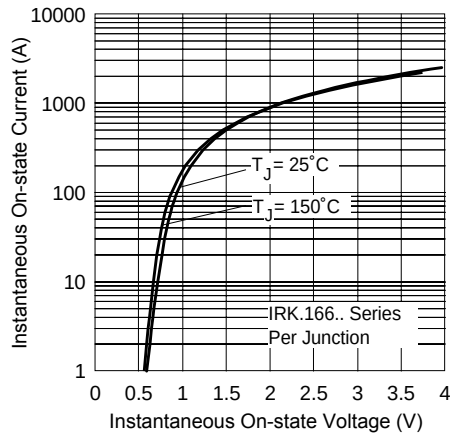


Fig.28 - On State Voltage Drop Characteristics

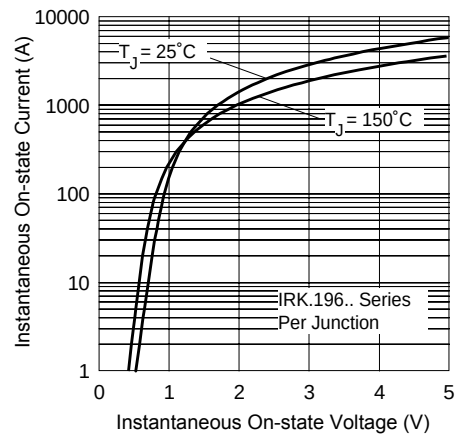


Fig.29 - On State Voltage Drop Characteristics

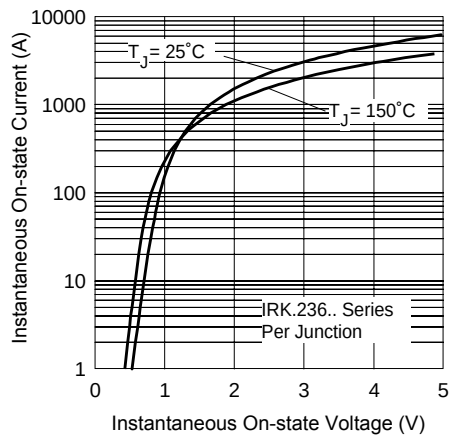


Fig.30 - On State Voltage Drop Characteristics

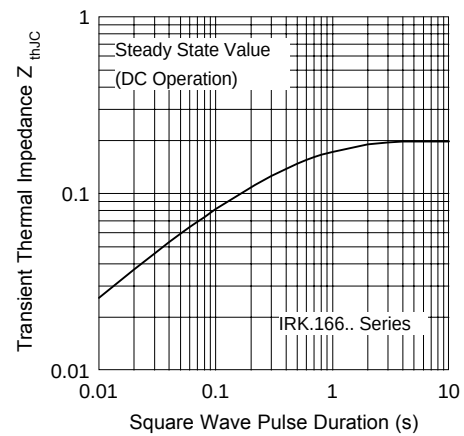


Fig.31 - Thermal Impedance Z_{thJC} Characteristics

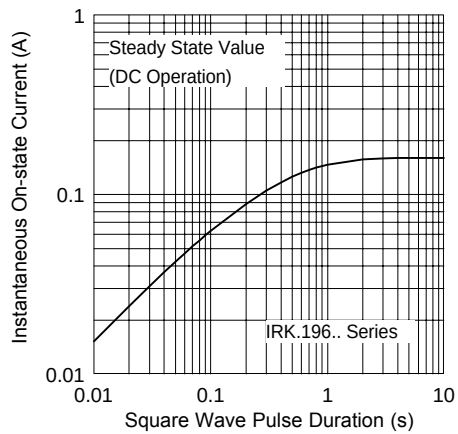


Fig.32 - Thermal Impedance Z_{thJC} Characteristics

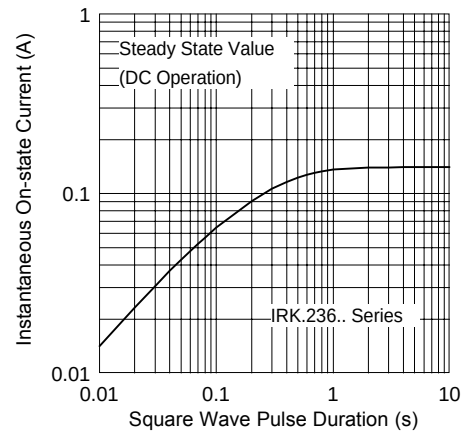


Fig.33 - Thermal Impedance Z_{thJC} Characteristics

IRK.166, .196, .236 Series

Bulletin I27116 rev. C 03/02

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Data and specifications subject to change without notice.
This product has been designed and qualified for Multiple Level.
Qualification Standards can be found on IR's Web site.

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